

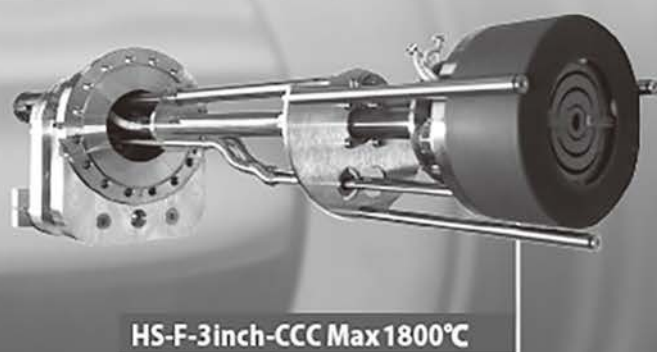
Ceramic Top Heaters Max1800C



CTH-S-2inch-NiCr
Max800°C



CTH-F-3inch-SiC Max1800°C



HS-F-3inch-CCC Max1800°C

● SUBSTRATE Heater for UHV thin film deposition

■ [Ceramic Top Heater Max1800°C] ■ [Hot Stage] RF/DC bias, rotation & Z-shift
Heater stages for substrate heating, wafer heating and sample heating & manipulation

Bench Top thin film deposition

Magnetron Sputtering

nanoPVD-S10A



Thermal evaporation for metal & Organic

nanoPVD-T15A

Benchtop Wafer Annealing

ANNEAL



● Benchtop thin film deposition series

- nanoPVD-S10A...3 sources for 2" targets, RF and DC PSU, 3 x MFC
- nanoPVD-T15A...2 for low temp evaporator, up to 2 sources for organics
- ANNEAL...Substrate annealing up to 1000 °C with precision atmosphere control